

PRM® Regulator

PRM48DH480T250B03





DC to DC Regulator

FEATURES

- Optimized for VR12.0
- 48V (38 to 60 V_{IN}), non-isolated ZVS buck-boost regulator
- 5 to 55 V adjustable output range
- Building block for high efficiency DC-DC systems
- 145W Output Power in 0.57 in² footprint
- 97% typical efficiency, at full load
- 1,342 W/in³ (82 W/cm³) Power Density
- Enables a 48 V to 1.2 V, 130 A isolated, regulated solution with total footprint of 1.7in² (11cm²)
- Flexible "Remote Sense" architecture optimizes regulation / feedback loop design to fit application requirements
- Current Feedback signal allows dynamic adjustment of current limit setpoint
- 9.32 MHrs MTBF (MIL-HDBK-217Plus Parts Count)

TYPICAL APPLICATIONS

- High Efficiency Server Processor and Memory Power
- High Density ATE system DC-DC power
- Telecom NPU and ASIC core power
- LED drivers
- High Density Power Supply DC-DC rail outputs
- Non-isolated power converters

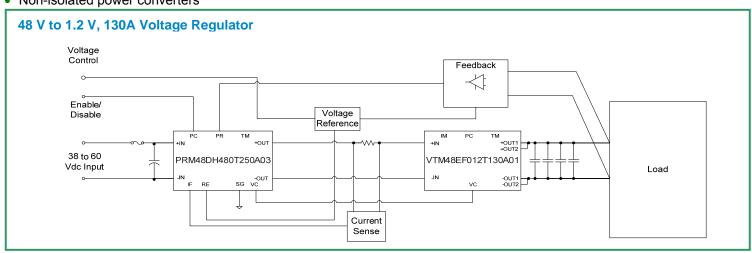
DESCRIPTION

The VI Chip PRM[®] Regulator is a high efficiency converter, operating from a 38 to 60 Vdc input to generate a regulated 5 to 55 Vdc output. The ZVS Buck - Boost topology enables high switching frequency (~1.5 MHz) operation with high conversion efficiency. High switching frequency reduces the size of reactive components enabling power density up to 1,342 W/in³.

The half VI Chip package is compatible with standard pickand-place and surface mount assembly processes with a planar thermal interface area and superior thermal conductivity.

In a Factorized Power Architecture™ system, the PRM48DH480T250B03 and downstream VTM™ transformer minimize distribution and conversion losses in a high power solution.

An external control loop and current sensor maintain regulation and enable flexibility both in the design of voltage and current compensation loops to control of output voltages and currents.





1.0 ABSOLUTE MAXIMUM RATINGS

The ABSOLUTE MAXIMUM ratings below are stress ratings only. Operation at or beyond these maximum ratings can cause permanent damage to device. Electrical specifications do not apply when operating beyond rated operating conditions. All voltages are specified relative to SG unless otherwise noted. Positive pin current represents current flowing out of the pin.

		Min	Max	Unit
PR		-0.3	10.5	V
FR			±10	mA
PC		-0.3	5.7	V
			±10	mA
TM		-0.3	5.7	V
11WI			±1	mA
+IN to -IN		-1	70	V
VS		-0.5	10.5	V
v3			±100	mA
SG			±100	mA
IF		-0.5	5.7	V
RE		-0.3	5	V
VC to -OUT		-0.5	18	V
VC t0 =001			±1.8	Α
+OUT to -OUT		-1	62	V
Output Current			±5.5	Α
Operating Analog IC Junction Temperature		-40	125	°C
Storage Temperature		-40	125	°C

2.0 ELECTRICAL CHARACTERISTICS

Specifications apply over all line and load conditions, T_J = 25 °C and output voltage from 20V to 55V, unless otherwise noted. Boldface specifications apply over the temperature range of 0 °C < T_J < 125 °C.

V _s Sew Rate			ELECTRICAL CHARACTERISTICS				
Main Typ Max							
POWER FILE No.							
Injort Voltage range		Symbol	Conditions / Notes	Min	Тур	Max	Unit
V _S Sew Rate	POWER INPUT SPECIFICATION						
No. Load Power Dissipation	Input Voltage range			38	48	60	V
Input Quiescent current Ioc Ioc Input Current Ioc Input Current Ioc Input Current Ioc Io	V _{IN} Slew Rate	dV _{IN} /dt	0 < V _{IN} < 18 V	0.001		1000	V/ms
Since power applied. Since power applied	No Load Power Dissipation	P _{NL}	PC High, V _{IN} = 48 V, V _{OUT} = 48 V		2.2	4	w
Injust Current Injust Computed Injust Computed Injust Capacitance (Internal) Effective value, V _N = 48 V, V _{OUT} = 48 V See Fig. 20 Injust Capacitance (Internal) Effective value, V _N = 48 V (see Fig. 20 Injust Capacitance (Internal) Effective value, V _N = 48 V, V _{OUT} = 48 V See Fig. 3 Injust Capacitance (Internal) See Fig. 16, SOA 20 48 55 V V _{OUT} = V _{OUT} V _{OUT} See Fig. 16, SOA 20 48 55 V V _{OUT} = V _{OUT} V _{OU}	Input Quiescent current	Iqc			5.0	10.0	mA
Injust Capacitance (Internal) Cit. Nat. Cell Effective value, V _{NI} = 48 V (see Fig. 20) Justice (Internal) ESR R _{Cit.} SR R _{Ci}	Input Current	lin ne			5.5	5.7	Δ
Doubget Dou			Zarodno rado, rije i o r (oco rig. 20)				
Output Voltage range		- sciii					111122
Output Current Output Current Output Current (Peak) Output Current (Internal) Courr Internal December 1		.,	0. 5: 40.004				
Output Discharge current Pask				20	48		V
Court Cour						4	- Δ
Output Turn-ON Delay Tot Tops + Total Tops + Town From PC pin release to Vogr. PC floating (200 mm) applied (200 mm)	Output Current (Peak)					4	
Top: +Ton From Vin applied to Voor, P C floating Equal input, output and PR voltage at full load; Vin = 48 V, Voor = 48 V, exclusive of current limit \$\frac{1}{2}\$	Output Power	Pout				145	W
Current Sharing accuracy	Output Turn-ON Delay	T _{ON}			20		μS
Current Sharing accuracy Courrent Sharing and Mark Sharing accuracy Courrent Sharing accuracy Courrent Sharing and Mark Sharing accuracy Courrent Sharing accura	Output Turn-Oil Belay	T _{OFF} +T _{ON}			18.02		ms
Over time, trim, and temperature: exclusive of current limit 95 96.7 95 95 96.7 95 95 96.7 95 95 95 95 95 95 95 9							%
Chef line, t.mm, and temperature; exclusive of current limit Signature S	Current Sharing accuracy	I _{OUT_Ps}	Equal input, output and PR voltage at full load;			See sec	0/
Fifticiency Figure Figu			Over line, trim, and temperature; exclusive of current limit			10.6	/0
50% load; over temperature				95.3	96.7		%
Output Discharge current I _{QD} N/A mA Output Voltage Ripple Vout prep Court at 0 F, I _{OUT} = 4.17 A, V _{IN} = 48 V, V _{OUT} = 48 V, 20 MHz BW 700 1050 mV Output Logacitance (Internal) Court int Court int Effective value, V _{OUT} = 48 V (see Fig. 20) 2 μF Output Capacitance (Internal) ESR R _{Cout} 3 mΩ mΩ POWERTRAIN PROTECTIONS Input Undervoltage Turn-ON V _{IN UVLO} - Instantanous powertrain shutdown, latched after T _{BLNK} 36.36 37.7 V Input Undervoltage Turn-OFF V _{IN UVLO} - Instantanous powertrain shutdown, latched after T _{BLNK} 32.1 33.56 V Input Overvoltage Turn-OFF V _{IN UVLO} - Instantanous powertrain shutdown, latched after T _{BLNK} 60.6 63.05 V Overcurrent (IF) and Input Overvoltage Turn-OFF V _{IN UVLO} - Instantanous powertrain shutdown, latched after T _{BLNK} 50 120 150 μs Overlundevroltage Turn-OFF V _{IN UVLO} - Instantanous powertrain shutdown, latched after T _{BLNK} 50 120 150 μs Overlundevroltage Turn-OFF V _{IN UVLO} - Instantanous powertrain shutdown, latched after T _{BLNK} 50 120 150 μs Overlundevroltage Turn-OFF V _{IN UVLO} - Instantanous powertrain shutdown, latched after V _{SU} - V _I Instantanous powertrain shutdown, latche	Efficiency			93			%
Output Voltage Ripple Vout PP Cout EXT = 0 F, Iout = 4.17 A, VIN = 48 V, VOUT = 48 V, 20 MHz BW 700 1050 mV Output Loquacitance (Internal) Cout Int Co			50% load; over temperature	88			%
Output Inductance (Parasitic) Output Capacitance (Internal) Output Capacitance (Internal) Cour INT Effective value, Vour = 48 V (see Fig. 20) 2	Output Discharge current	I _{OD}			N/A		mA
Output Capacitance (Internal) COUT_INT Effective value, VOUT = 48 V (see Fig. 20) 2 μF Output Capacitance (Internal) ESR RCout 3 mΩ POWERTRAIN PROTECTIONS Input Undervoltage Turn-ON VIN_UVLO-VIN_UVLO	Output Voltage Ripple	V _{OUT PP}			700	1050	mV
Output Capacitance (Internal) ESR R _{Cout} POWERTRAIN PROTECTIONS Input Undervoltage Turn-ON V _{IN UVLO} - Input Undervoltage Turn-OFF V _{IN UVLO} - Input Undervoltage Turn-ON Input Overvoltage Turn-ON V _{IN UVLO} - Input Undervoltage Turn-ON Input Overvoltage Turn-OFF V _{IN UVLO} - Input Undervoltage Turn-OFF V _{IN UVLO} - Instantanous powertrain shutdown, latched after T _{BLNK} 60.6 60.6 63.05 V Input Overvoltage Turn-OFF V _{IN UVLO} - Overcurrent (IF) and Input Overvoltage Blanking Time 50 Output Overvoltage Threshold V _{OUT OVLO} + NIA NIA NIA NI	Output Inductance (Parasitic)	LOUT PAR			2.5		
POWERTRAIN PROTECTIONS Input Undervoltage Turn-ON V_IN_UVLO+	Output Capacitance (Internal)	C _{OUT INT}	Effective value, V _{OUT} = 48 V (see Fig. 20)		2		μF
Input Undervoltage Turn-ON VIN UVLO+ Instantanous powertrain shutdown, latched after T _{BLNK} 36.36 37.7 V Input Undervoltage Turn-OFF VIN UVLO- Input Overvoltage Turn-OFF VIN UVLO- Input Overvoltage Turn-OFF VIN OVLO- Instantanous powertrain shutdown, latched after T _{BLNK} 60.6 63.05 V V V V V V V V V	Output Capacitance (Internal) ESR	R _{Cout}			3		mΩ
Input Undervoltage Turn-OFF V_IN_UVLO- Instantanous powertrain shutdown, latched after T _{BLNK} 60.6 63.05 V V V V V V V V V	POWERTRAIN PROTECTIONS						
Input Undervoltage Turn-OFF VIN UVLO- Input Overvoltage Turn-OFF VIN OVLO- Input Overvoltage Turn-OFF VIN OVLO- Instantanous powertrain shutdown, latched after T _{BLNK} 60.6 63.05 V V V V V V V V V V V V V V V V V V	Input Undervoltage Turn-ON	V _{IN UVLO+}	Instantanous powertrain shutdown, latched after T _{BLNK}		36.36	37.7	V
Input Overvoltage Turn-ON V_IN_OVLO+ Instantanous powertrain shutdown, latched after T _{BLNK} 60.6 63.05 V	Input Undervoltage Turn-OFF			32.1	33.56		V
Input Overvoltage Turn-OFF	Input Overvoltage Turn-ON		Instantanous powertrain shutdown, latched after T _{BLNK}	60.6	63.05		V
Over/Undervoltage Blanking Time TBLNK 30 120 150 μs Output Overvoltage Threshold Vour OvLO+ N/A N/B V C C C D N/B C C D M S Y N/B Y S <td>Input Overvoltage Turn-OFF</td> <td></td> <td></td> <td></td> <td>64.12</td> <td>66</td> <td>V</td>	Input Overvoltage Turn-OFF				64.12	66	V
Over/Undervoltage Blanking Time Output Overvoltage Threshold VouT OVLO+ Thermal Shutdown Setpoint Ty orp Overtemperature and PC Shutdown Response Time Short Circuit Vout Threshold Short Circuit Vout Threshold Vsc vout Short Circuit Vour Recovery Threshold Vsc vout Short Circuit Vor Recovery Threshold Vsc vout Short Circuit Typ Recovery Threshold Vsc vout Tsc Short Circuit Table Itale Recovery Time Tsc O,1 ms	Overcurrent (IF) and Input	-		50	400	450	
Output Overvoltage Threshold VouT OVLO+ N/A N/A N/A N/A N/A N/A N/A N/	Over/Undervoltage Blanking Time	BLNK		50	120	100	μs
Covertemperature and PC Shutdown T_PROT 2 µs µs	Output Overvoltage Threshold	V _{OUT OVLO+}	N/A	N/A	N/A	N/A	V
PROT 2 μs	Thermal Shutdown Setpoint	T _{J OTP}	Instantaneous, latched shutdown; guaranteed by design, not production tested; V _{TM} = 4.03V	130			°C
Short Circuit Vout Threshold Vsc vour 3.42 V	Overtemperature and PC Shutdown	-			0		
Short Circuit Vout Recovery Threshold Vsc voutra Vs	Response Time	PROT			2		μs
Short Circuit Vout Recovery Threshold $V_{SC\ VOUTR}$ 4.53 V Short Circuit Vpr Threshold $V_{SC\ VPR}$ 7.1 V Short Circuit Vpr Recovery Threshold $V_{SC\ VPR}$ 7.1 V Short Circuit Timeout 5.5 Short Circuit fault latched after $V_{SC\ VOUT}$ and $V_{SC\ VPR}$ thresholds persist for this time 2.0 ms Short Circuit Fault Recovery Time $V_{SC\ VPR}$ 5.1 ms		V _{SC VOUT}			3.42		V
Short Circuit Vpr Threshold Vsc VPR 7.1 V Short Circuit Vpr Recovery Threshold Vsc VPR 6.9 V Short Circuit Typr Recovery Threshold Vsc VPR 6.9 V Short Circuit Timeout Tsc Short Circuit fault latched after Vsc Vout and Vsc VPR thresholds persist for this time 20 ms Short Circuit Fault Recovery Time TscR 0.1 ms	Short Circuit Vout Recovery Threshold	V _{SC VOUTR}			4.53		V
Short Circuit Vpr Recovery Threshold Vsc vprR Short Circuit Timeout Tsc Short Circuit fault latched after Vsc vout and Vsc vpr thresholds persist for this time 20 ms Short Circuit Fault Recovery Time Tscr 0.1 ms	Short Circuit Vpr Threshold				7.1		V
Short Circuit Timeout T_{SC} Short Circuit fault latched after $V_{SC \ VOUT}$ and $V_{SC \ VPR}$ thresholds persist for this time 20 ms Short Circuit Fault Recovery Time T_{SCR}	Short Circuit Vpr Recovery Threshold				6.9		V
Short Circuit Fault Recovery Time T _{SCR} 0.1 ms	Short Circuit Timeout	T _{SC}	Short Circuit fault latched after V _{SC VOUT} and V _{SC VPR} thresholds persist for this time		20		ms
Output Power Limit PPROT 200 W	Short Circuit Fault Recovery Time	T _{SCR}			0.1		ms
	Output Power Limit	P _{PROT}		200			W

3.0 SIGNAL CHARACTERISTICS

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DE

Voltage Source

Reference Enable

Specifications apply over all line and load conditions, T_J = 25 °C and Output Voltage from 20V to 55V, unless otherwise noted. Boldface specifications apply over the temperature range of 0 °C < T_J < 125 °C.

Primary Control	PC							
. The PC pin enables and disables the	PRM; When held	below ~2.4 V the PRM will be disat	oled.					
. In PRM array configurations, PC pins	should be connected	cted in order to synchronize startup						
· PC pin is 5 V during normal operation	1.							
• It is a weak pull-down during any fault	mode excluding:	short circuit. PC is a strong pull-dov	vn to SG if a	Short Circuit fault is latched.				
Signal Type	State	Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
Analog Output	Regular	PC Voltage	V _{PC}		4.7		5.3	V
	Operation	PC Available Current	I _{PC_OP}		1.8			mA
Analog Output	Startup	PC Source Current	I _{PC_EN}	After T _{OFF}		90		μА
	Startup	Minimum Time to Start	T _{OFF}	Section 5.0	6.8	12.3	17.8	ms
	Startup	PC Enable Threshold	V _{PC_EN}			2.50	3.20	V
Digital Input / Output		PC Disable Threshold	V _{PC DIS}		1.75	2.40		V
Standby	Standby	PC Resistance to disable	R _{PC_EXT}	Max Resistance to SG required to disable the PRM			300	Ω
Digital Output [Short Circuit Fault]	Fault	PC Sink Current to SG	I _{PC_SC}	Short circuit, PC Voltage 1 V or above		25		mΑ
Digital Output [All other Faults]	Fault	PC Sink Current to ~1V	I _{PC FAULT}	Temperature, Over- and Under-Voltage, Overcurrent		10		μА

 Intended to power feedback components and/or auxiliary circuits. • 9 V, 5mA regulated voltage source • With > 5% output load, VS ripple typically 100mV Signal Type Conditions / Notes Min Max State Attribute Symbol Тур Unit VS Voltage 8.55 9.00 9.45 ν \mathbf{V}_{VS} Regular VS Available Current I_{vs} mΑ Operation lout = 0A, Cvs_ext=0. Maximum specification Analog Output VS Voltage Ripple V_{VS_PP} 330 500 m۷ includes powertrain operation in burst mode. VS Capacitance (External) 0.04 C_{VS_EXT} μF Transition T_{FR VS} From fault recognition to VS = 1.5 V VS Fault Response Time μs

Veletelice Fliable	NL.							
 RE signals successful startup and po 	wertrain ready to	operate						
· Intended to power and enable the fee	dback circuit refer	rence						
• 3.3V, 8mA regulated voltage source								
Signal Type	State	Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
		RE Voltage	V _{RE}		3.0	3.3	3.6	V
	Regular	RE Available Current	I _{RE}		8.0			mA
	Operation	RE Regulation	% _{RE}	across load and temperature		±2.5		%
Analog Output		RE Voltage Ripple	V _{RE_PP}	includes powertrain in burst mode		105		mV
		PC to RE Delay	T _{PC_RE}	Fault detected		100		μs
	Transition	RE Capacitance (External)	C _{RE_EXT}				0.1	μF
		VS to RE Delay	т	VS = 8.1 V to RE high V > V		1		me

Control Node	PR							
Modulator control node input								
0.5mA constant current sink when a	xternally driven							
0.79V, up to 2mA voltage source wh	en externally pulle	d low						
Signal Type	State	Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
		PR Voltage Active Range	V_{PR}		0.79		7.40	V
Analog Input Operation	Regular	PR Source Current	I _{PR}	V _{PR} ≤ 0.79V			2	mΑ
	Operation	PR Sink Current	I _{PR_Low}	V _{PR} > 0.79V	250	500	750	μА
	PR Resistance to SG (Internal)	Ron			93.3		kO	

Current Feedback	IF.							
 A voltage proportional to the PRM ou 	tput current must	be supplied externally to the IF pin in	order for the	e device to properly protect overcurrent events and to	enable output	current limit	(clamp)	
Overcurrent protection trip will cause	instantaneous po	wertrain disable, latched after T _{BLNK}						
Signal Type	State	Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
Analog Input		Current Limit (clamp) Threshold	V _{IF_IL}	V _{IN} = 48 V; T _J = 25 °C	1.90	2.00	2.10	
	Regular Operation	Overcurrent Protection Threshold	V _{IF_OC}	Not Production Tested; Guaranteed by Design; $T_J = 25 ^{\circ}\text{C}$	2.58	2.69	2.80	V
	Operation	IF Input Impedance	R _{IF}		2.11	2.13	2.15	kΩ
		Current Limit Bandwidth	BWIL			2		kHz

Temperature Monitor	TM							
The TM pin monitors the internal tem	perature of the PR	M analog control IC to within ±5 °C.						
• Room temperature setpoint is ~ 3 V,	approximate gain i	is 10 mV/°C.						
• "Power Good" flag to verify that the P	RM is operating							
Signal Type	State	Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
	Decides	TM Voltage	V _{TM}	Full temperature range	2.12		4.04	V
		TM Voltage reference	V _{TM_AMB}	T _J = 27 °C	2.94	3.00	3.06	V
Analog Output	Regular Operation	TM Voltage Ripple	V _{VS_PP}	powertrain in burst mode		210		mV
	Орстаноп	TM Available Current	I _{TM}		100			μА
		TM Gain	A _{TM}			10		mV/°C
Digital Output [Fault Flag] F	Fault or Standby	TM Disabled Current	I _{TM DIS}	DC state with TM Voltage +/- 0.5V. This is a high		0.0		mA
			- IIVI_DIS	limnedance state	V/////////////////////////////////////	1		4

Signal Ground SG

• All control signals must be referenced to this pin, with the exception of VC

• SG is internally connected to -IN and -OUT

- 30 is internally connected to five and -	.001							
Signal Type	State	Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
Analog Input / Output	Any	Maximum Allowable Current	I _{sg}		-100		100	mA

VTM Control VC

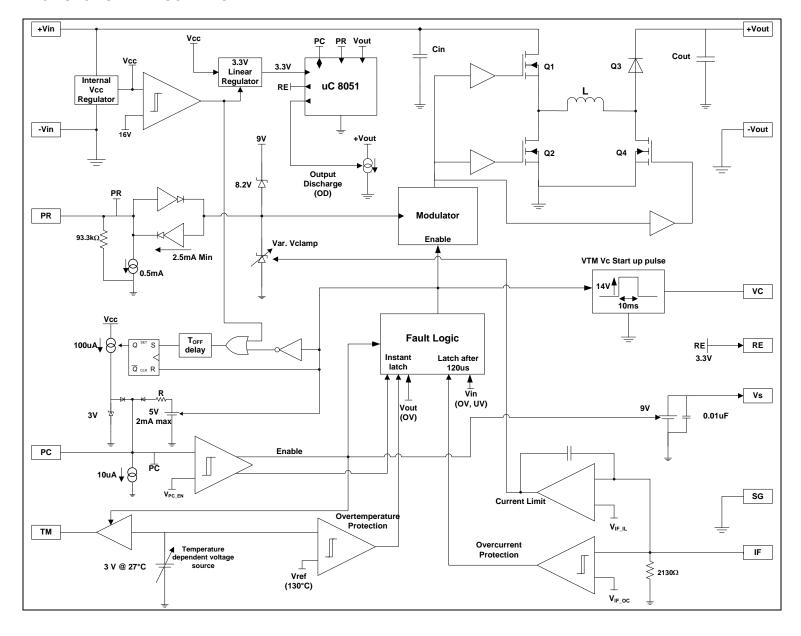
• Used to synchronize start up of downstream VTM converter.

• 14V nominal, 10ms voltage pulse

• If not used, must be resistively terminated to -OUT

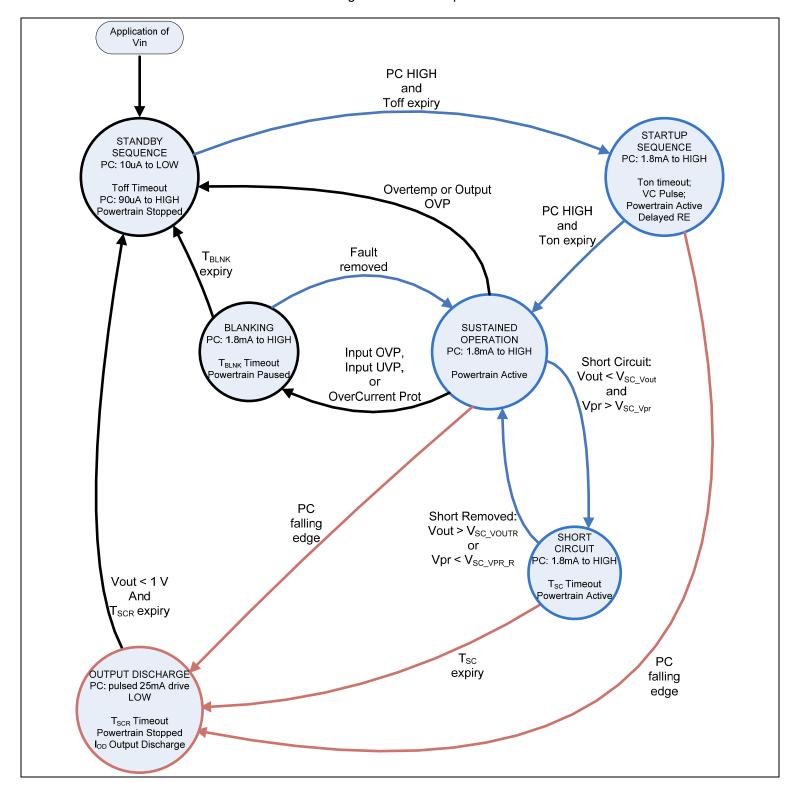
Signal Type	State	Attribute	Symbol	Conditions / Notes	Min	Тур	Max	Unit
		VC Voltage	V _{VC}	$R_{VC} = 68\Omega$	13			V
	VC Current Limit	I _{VC}	V _C = 14 V, V _{IN} > 20 V	200	500		mA	
Analog Output	Startup	VC duration	T _{VC}		7	10		ms
		VC Slew Rate	dVC/dt	$R_{VC} = 1k\Omega$		20		V/µs

4.0 FUNCTIONAL BLOCK DIAGRAM



HIGH LEVEL FUNCTIONAL STATE DIAGRAM

Conditions that cause state transitions are shown along arrows. Sub-sequence activities listed inside the state bubbles.

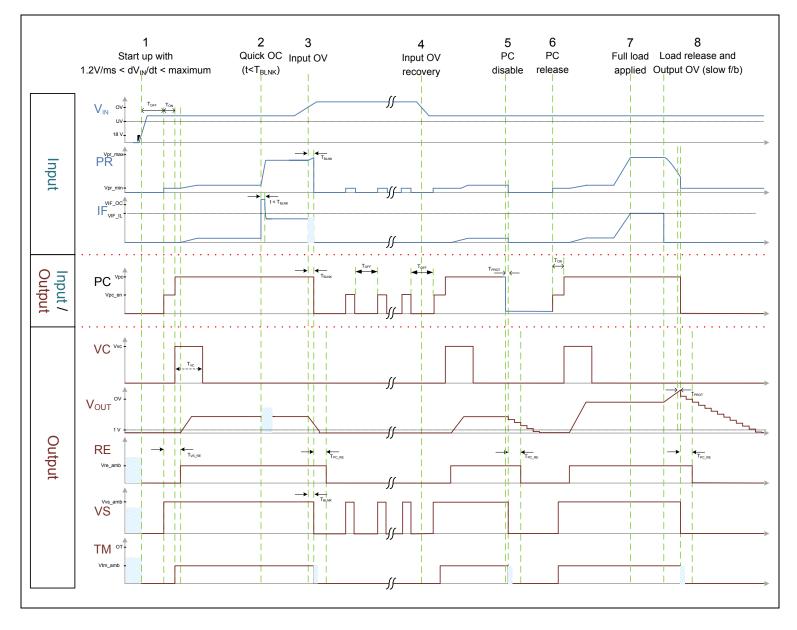


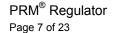


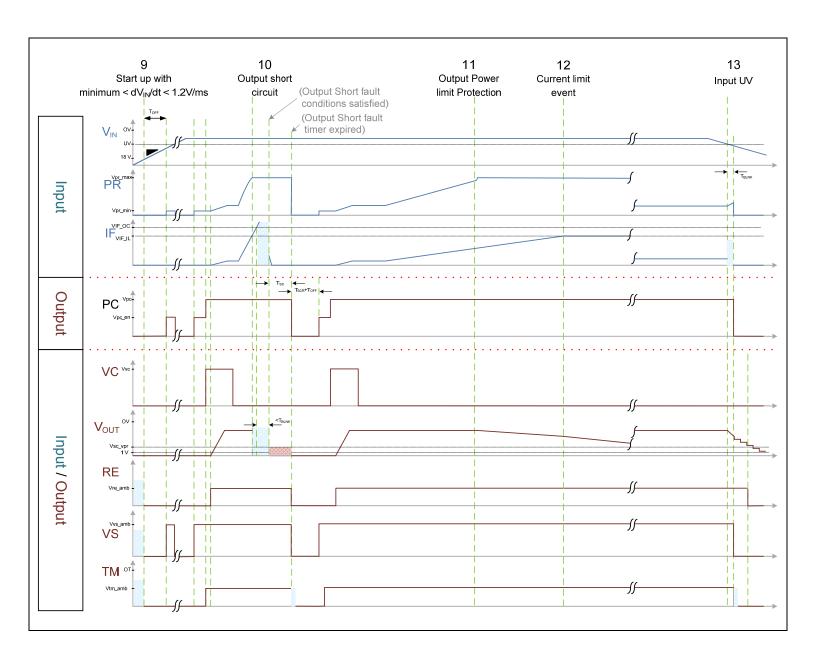
5.0 TIMING DIAGRAMS

Module Inputs are shown in blue; Module Outputs are shown in brown; Timing diagrams assumes the following:

- Single PRM® (no array)
- > VS powers error amplifier
- > RE powers voltage reference and output current transducer
- > I_{OUT} is sensed, scaled, and fed back to IF pin such that IF = 2.00 V at full load







6.0 APPLICATIONS CHARACTERISTICS

The following figures present typical performance at $T_C = 25^{\circ}C$, unless otherwise noted. See associated figures for general trend data.

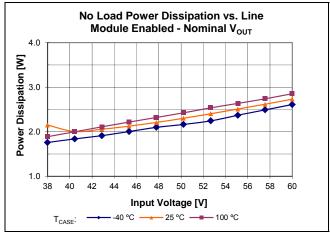


Figure 1 - No load power dissipation vs. V_{IN} , module enabled

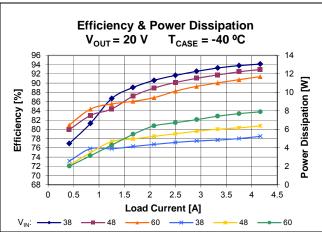


Figure 3 – Total efficiency and power dissipation vs. V_{IN} and I_{OUT} , V_{OUT} = 20V, T_{CASE} = -40°C

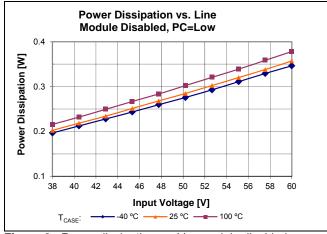


Figure 2 - Power dissipation vs. V_{IN}, module disabled

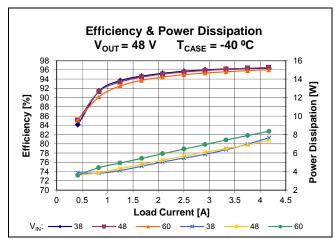


Figure 4 – Total efficiency and power dissipation vs. V_{IN} and I_{OUT} , V_{OUT} = 48V, T_{CASE} = -40°C

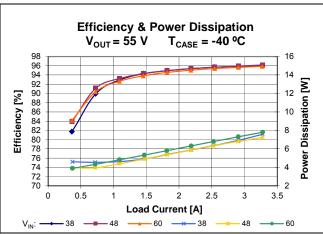


Figure 5 – Total efficiency and power dissipation vs. V_{IN} and I_{OUT} , V_{OUT} = 55V, T_{CASE} = -40°C

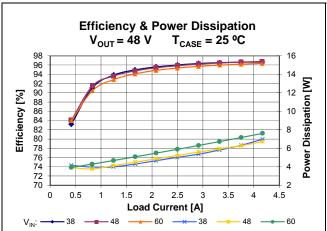


Figure 7 – Total efficiency and power dissipation vs. V_{IN} and I_{OUT} , V_{OUT} = 48V, T_{CASE} = 25°C

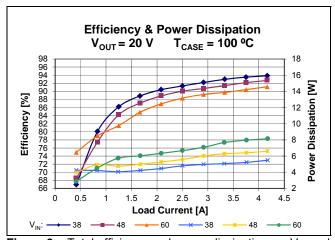


Figure 9 – Total efficiency and power dissipation vs. V_{IN} and I_{OUT} , V_{OUT} = 20V, T_{CASE} = 100°C

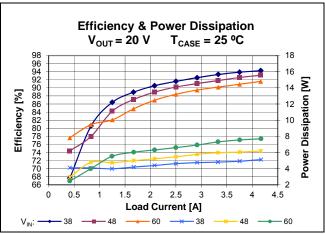


Figure 6 – Total efficiency and power dissipation vs. V_{IN} and I_{OUT} , V_{OUT} = 20V, T_{CASE} = 25°C

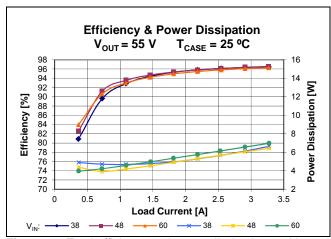


Figure 8 – Total efficiency and power dissipation vs. V_{IN} and I_{OUT} , V_{OUT} = 55V, T_{CASE} = 25°C



Figure 10 – Total efficiency and power dissipation vs. V_{IN} and I_{OUT} , V_{OUT} = 48V, T_{CASE} = 100°C

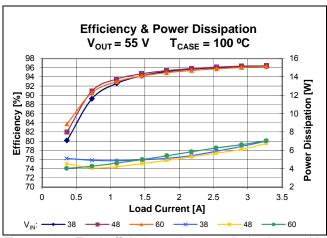


Figure 11 – Total efficiency and power dissipation vs. V_{IN} and I_{OUT} , V_{OUT} = 55V, T_{CASE} = 100°C

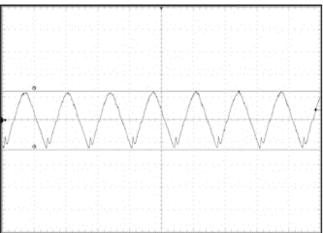


Figure 13 – Typical output voltage ripple waveform, 200 mV/div, 500 ns/div $T_{CASE} = 30^{\circ}C$, $V_{IN} = 48V$, $V_{OUT} = 48V$, $I_{OUT} = 3.2$ A, no external output capacitance.

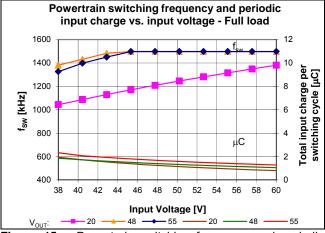


Figure 15 – Powertrain switching frequency and periodic input charge vs. V_{IN} , V_{OUT} ; I_{OUT} = 3.2 A

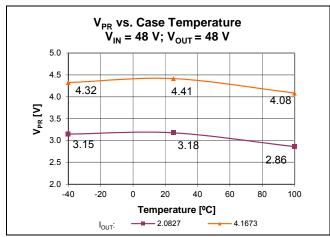


Figure 12 – Typical control node voltage vs. T_{CASE} , and I_{OUT} ; V_{IN} = 48V, V_{OUT} = 48V

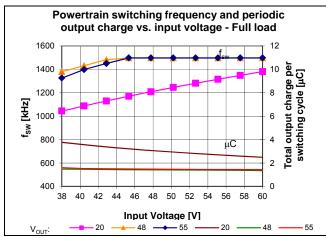


Figure 14 – Powertrain switching frequency and periodic output charge vs. V_{IN} , V_{OUT} ; $I_{OUT} = 3.2 \text{ A}$

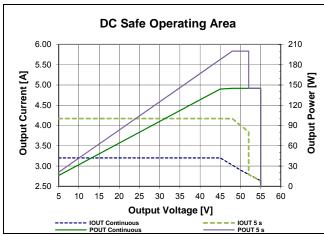


Figure 16 – DC Output Safe Operating Area

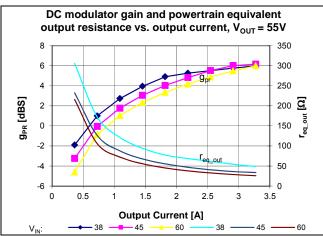


Figure 17 – Powertrain characteristics vs. I_{OUT;} Resistive load, V_{OUT} = 55V, various V_{IN}

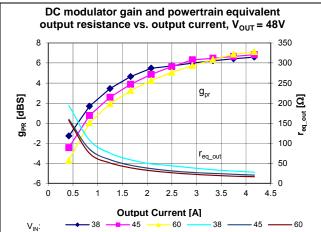


Figure 19 – Powertrain characteristics vs. I_{OUT}; Resistive load, V_{OUT} = 48V, various V_{IN}

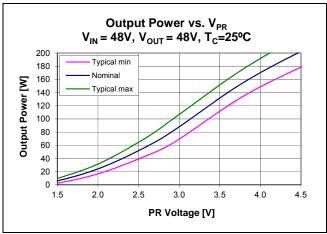


Figure 21 – Output Power vs. V_{PR} ; V_{IN} = 48V, V_{OUT} = 48V, T_{CASE} = 25°C

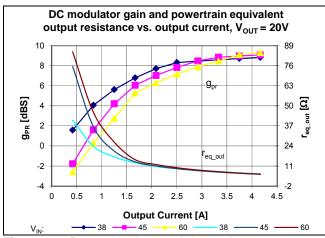


Figure 18 – Powertrain characteristics vs. I_{OUT} ; Resistive load, V_{OUT} = 20V, various V_{IN}

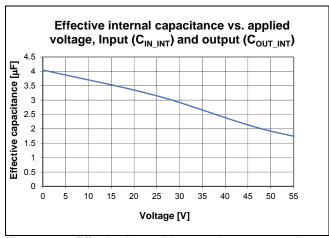


Figure 20 – Effective internal input and output capacitance vs. voltage – ceramic type

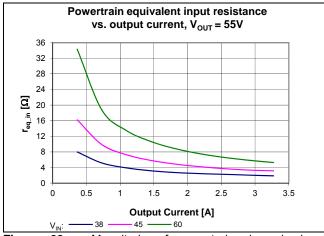


Figure 22 – Magnitude of powertrain dynamic input impedance vs. V_{IN} , I_{OUT} ; V_{OUT} = 55V

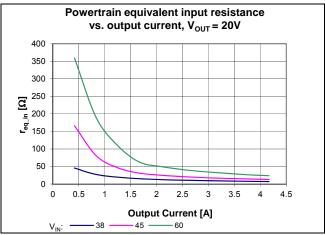


Figure 23 – Magnitude of powertrain dynamic input impedance vs. V_{IN}, I_{OUT}; V_{OUT} = 20V

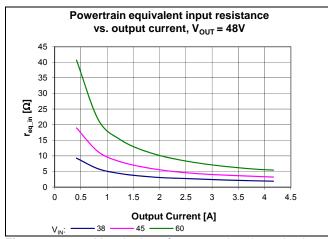


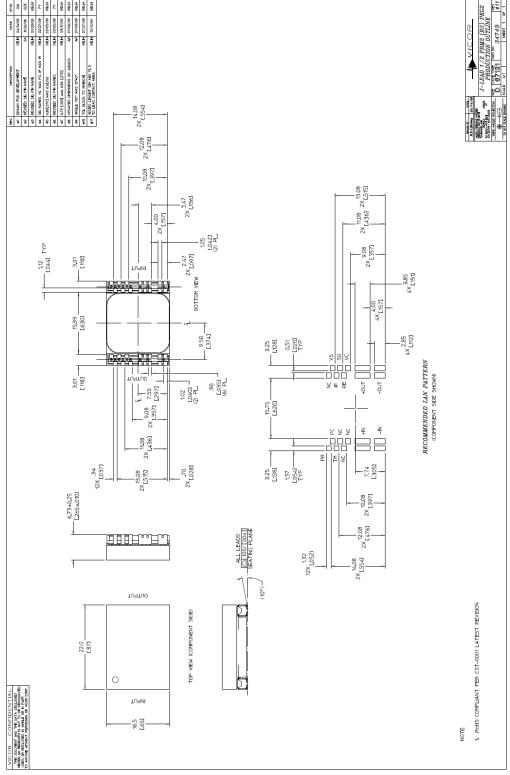
Figure 24 – Magnitude of powertrain dynamic input impedance vs. V_{IN}, I_{OUT}; V_{OUT} = 48V

7.0 GENERAL CHARACTERISTICS

Specifications apply over all line and load conditions, $T_J = 25$ °C and Output Voltage from 20V to 55V, unless otherwise noted. Boldface specifications apply over the temperature range of 0 °C < T_J < 125 °C.

		GENERAL CHARACTERISTICS				
		and output Voltage from 20V to 55V unless otherwise noted;				
		re range of -40 °C < T _J < 125 °C (T-Grade); All Other specifications are at T _J = 25 °C unless oth Conditions / Notes		T		I Date
Attribute MECHANICAL	Symbol	Conditions / Notes	Min	Тур	Max	Unit
Length	L			22.0 / [0.87]		
Width	W		16.3 / [0.64]	16.5 / [0.65]	16.8 / [0.66]	mm / [in]
Height	Н		[0.255]	[0.265]	[0.275]	mm / [in]
Volume	Vol	No Heatsink		2.44 / [0.15]		cm ³ /[in ³
Weight	W			7		g
		Nickel	0.51		2.03	
Lead Finish		Palladium	0.02		0.15	μm
		Gold	0.003		0.050	
THERMAL						
Operating Temperature	T,I		0		125	°C
Operating Case Temperature	T _C	Any operating condition	0		100	°C
Thermal Capacity				5		Ws/°C
ASSEMBLY						
Peak Compressive Force Applied to		Supported by J-Lead only			3	Ibs
Case (Z-axis)	-		40		5.33	lbs / in ²
Storage Temperature	T _{ST}	Human Body Model, "JEDEC JESD 22-A114C.01"	-40		125	°C
ESD Rating	ESD _{HBM}		1000			V
	ESD _{CDM}	Charged Device Model, "JEDEC JESD 22-C101D"	400			
SOLDERING						
		MSL 4 (Datecode 1528 and later)			245	°C
Peak Temperature During Reflow					240	°C
Maximum Time Above [217] °C					150	S
Peak Heating Rate During Reflow				1.5	2	°C/s
Peak Cooling Rate Post Reflow				2.5	3	°C/s
SAFETY and RELIABILITY						
MTDE		Telcordia Issue 2 - Method I Case 1; Ground Benign, Controlled		5.41		MHrs
MTBF		MIL-HDBK-217Plus Parts Count - 25C Ground Benign, Stationary, Indoors / Computer Profile		6.22		MHrs
		cTUV _{US}				
Agency Approvals / Standards		CE Mark				
		CE Marked for Low Voltage Directive and RoHS Recast Directive, as applicable				

PRODUCT OUTLINE DRAWING AND RECOMMENDED PCB FOOTPRINT



8.0 PRODUCT DETAILS AND DESIGN GUIDELINES

8.1 Control pins description and characteristics

Control node (PR) is the input to the control node which determines the powertrain timing and ultimately the module output power (Figure 21). An internal 0.5mA current sink is always active. The bi-directional buffer between PR and the control node has two states. In normal operation, PR will be above the 0.79V switching threshold, and will drive the control node through the buffer. An internal 7.4V clamp determines the maximum output power that can be requested of the modulator.

When PR falls below 0.79 V, the converter will stop switching. An internal circuit clamps the modulator input control node to 0.79 V, and a buffer will source up to 2.5 mA out of the pin at that clamp level. For this reason, the output impedance of the amplifier driving PR must be taken into account. A rail-to-rail operational amplifier with low output impedance is always recommended.

The powertrain small signal (plant) response consists of a single pole determined by the load resistance, the powertrain equivalent output resistance, and the total output capacitance (internal and external to the module). Both the modulator gain and the equivalent output resistance vary as a function of line, load and output voltage, as shown in Figures 17, 18 and 19. As the load increases, the powertrain pole moves to higher frequency. As a result, the closed loop crossover frequency will be the

highest at full load and lowest at minimum load. Figure 25 shows a reference AC small-signal model.

Current feedback (IF) is the input for the module output overcurrent protection and current limit features (see functional block diagram in section 4.0). A voltage proportional to the powertrain output current must be applied to IF in order for overcurrent protection to operate properly.

If the IF voltage exceeds the IF pin's overcurrent protection threshold, the powertrain will stop switching. If the IF voltage falls below the overcurrent protection threshold within T_{BLANK} time, then the powertrain will immediately resumes switching. Otherwise a fault is latched.

The current limit threshold for the IF pin is set lower than the protection threshold. When the IF pin average voltage exceeds the current limit threshold, an internal integrator will activate a clamp amplifier which overrides the modulator input maximum level. This causes the powertrain to maintain a constant output current.

The bandwidth of this current limit integrator is significantly slower than that of the PR control node input. Therefore this current limit can not be used in lieu of properly compensating the (external) PR control loop to avoid exceeding maximum current or power ratings for the device.

If the IF pin is not driven, it must be resistively terminated to SG. A $1k\Omega$ resistor to SG is recommended in this case.

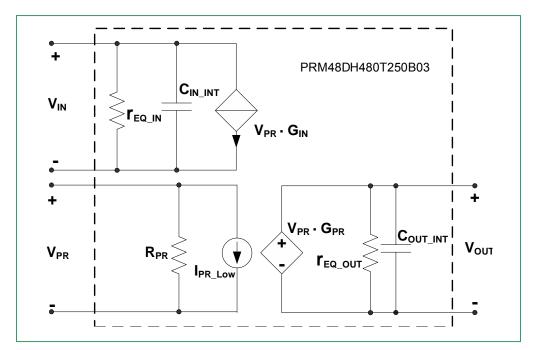


Figure 25 – PRM48DH480T250B03 AC small signal model

VTM Control (VC) pin supplies an initial V_{CC} voltage to downstream VTMs, enabling them and synchronizing their startup with the PRM[®]. The V_{CC} voltage is a pulse, typically 10 ms duration at 14 V.

If VC is not loaded by a VTM, it must be terminated with a 1 $k\Omega$ resistor to –VOut.

Primary Control (PC) is both an input and an output. It can provide the following features:

- Delayed start: upon application of voltage (>UVLO) to the module power input and after $T_{\text{OFF}},$ the PC pin will source a constant 90 μA current.
- Output disable: PC may be pulled down externally in order to disable the module. Pull down resistance should be less than 300 μ to SG.
- Fault detection flag: The PC 5 V voltage source is internally turned off when a fault condition is latched. Note that aside from the Short Circuit fault condition, PC does not have significant current sinking capability. Therefore in the case of an array of PRMs with interconnected PC pins, PC does not in general reflect the fault state of all PRMs. The common PC line will not disable neighboring modules when a fault is detected except for a latched Output Short Circuit fault. Conversely any unit in the array latching a Short Circuit fault will disable the array for $T_{\rm SCR}$.

Temperature Monitor (TM) pin outputs a voltage proportional to the absolute temperature of the converter analog control IC. It can be used to accomplish the following functions:

- Monitor the control IC temperature: The gain and setpoint of TM are such that the temperature, in Kelvin, of the PRM controller IC is equal to the voltage on the TM pin scaled by 100. (i.e. $3.0 \text{ V} = 300 \text{ K} = 27 \text{ }^{\circ}\text{C}$).
- Closed loop thermal management at the system level (e.g. variable speed fans or coolant flow)
- Fault detection flag: The TM voltage source is turned off as soon as a fault is detected. For system monitoring purposes (microcontroller interface) faults are detected on falling edges of TM.

Reference Enable (RE) pin outputs a regulated 3.3 V, 8 mA voltage source. It is enabled only after successful startup of the PRM powertrain (see chapters 5.0 and 6.0.) RE is intended to power the output current transducer and also the voltage reference for the control loop. Powering the reference generator with RE helps provide a controlled startup, since the output voltage of the system is able to track the reference level as it comes up.

Voltage Source (VS) pin outputs a gated (e.g. mirrors PC status), non-isolated, regulated 9 V, 5 mA voltage source. It can be used to power external control circuitry; it always leads RE.

Signal Ground (SG) pin provides a Kelvin connection to the PRM's internal signal ground. It should be used as the reference for PR, TM, IF, and should return all PC, VS and RE pin currents. In array configurations with common ground control circuits, a series resistor (\sim 1 Ω) is recommended in order to decouple power and signal current returns.

8.2 Control circuit requirements and design procedure

The PRM48DH480T250B03 is an intelligent powertrain module designed to fully exploit external output voltage feedback and current sensing sub-circuits. These two external circuits are illustrated in Figure 26, which shows an example of the PRM in a standalone application with local voltage feedback and high side current sensing. In general, these circuits include a precision voltage reference, an operational amplifier which provides closed loop feedback compensation, and a high side current sense circuit which includes a shunt and current sense IC.

The following design procedures refer to the circuit shown in Figure 26.

8.2.1 Setting the output voltage level

The output voltage setpoint is a function of the voltage reference and the output voltage sense ratio. With reference to Fig. 26, R1 and R2 form the output voltage sensing divider which provides the scaled output voltage to the negative input of the error amplifier; a dedicated reference IC provides the reference voltage to the positive input of the error amplifier. Under normal operation, the error amplifier will keep the voltages at the inverting and non-inverting inputs equal, and therefore the output voltage is defined by:

$$V_{OUT} = V_{ref} \cdot \frac{R1 + R2}{R2}$$

Note that the component R1 will also factor into the compensation as described in a later section.

It is important to apply proper slew rate to the reference voltage rise when the control loop is initially enabled. The recommended range for reference rise time is 1 ms to 9 ms. The lower rise time limit will ensure optimized modulator timing performance during startup, and to allow the current limit feature (through IF pin) to fully protect the device during power-up. The upper rise time limit is needed to guarantee a sufficient factorized bus voltage is provided to any downstream VTM input before the end of the VC pulse.



8.2.2 Setting the output current limit and overcurrent protection level

The current limit and overcurrent protection set points are linked, and scale together against the current sense shunt, and the gain of the current sense amplifier. The output of the current sense IC provides the IF voltage which has $V_{\text{IF_IL}}$ and $V_{\text{IF_OC}}$ thresholds for the two functions respectively. The set points are therefore defined by:

$$I_{IL} = \frac{V_{IF_IL}}{R_S \cdot G_{CS}}$$

and

$$I_{OC} = \frac{V_{IF_OC}}{R_S \cdot G_{CS}}$$

where G_{CS} is the gain of the current sense amplifier.

8.2.3 Control loop compensation requirements

In order to properly compensate the control loop, all components which contribute to the closed loop frequency response should be identified and understood. Figure 25 shows the AC small signal model for the module. Modulator DC gain G_{PR} and powertrain equivalent resistance r_{EQ_OUT} are shown. These modeling parameters will support a design cut-off frequency up to 50 kHz. Standard Bode analysis should be used for calculating the error amplifier compensation and analyzing the closed loop stability. The recommended stability criteria are as follows:

- 1) Phase Margin > 45° : for the closed loop response, the phase should be greater than 45° where the gain crosses 0dB.
- 2) Gain Margin > 10dB : The closed loop gain should be lower than -10dB where the phase crosses 0°.
- 3) Gain Slope = -20dB / decade : The closed loop gain should have a slope of -20dB / decade at the crossover frequency.

The compensation characteristics must be selected to meet these stability criteria. Refer to Figure 27 for a local sense, voltage-mode control example based on the configuration in Figure 26. In this example, it is assumed that the maximum crossover frequency (F_{CMAX}) has been selected to occur between B and C. Type-2 compensation (Curve IJKL) is sufficient in this case.

The following data must be gathered in order to proceed:

➤ Modulator Gain G_{PR}: See Figures 17, 18, 19

- Powertrain equivalent resistance r_{EQ}: See Figures 17, 18, 19
- Internal output capacitance: see Figure 20
- External output capacitance value

In the case of ceramic capacitors, the ESR can be considered low enough to push the associated zero well above the frequency of interest. Applications with high ESR capacitor may require a different type of compensation, or cascade control.

The system poles and zeros of the closed loop can then be defined as follows:

Powertrain pole, assuming the external capacitor ESR can be neglected:

$$R_{C_{OUT_EXT}} << \frac{r_{EQ_OUT} \cdot R_{LOAD}}{r_{EO_OUT} + R_{LOAD}}$$

Main pole frequency:

$$F_{P} \approx \frac{1}{2\pi \cdot \frac{r_{EQ_OUT} \cdot R_{LOAD}}{r_{EO_OUT} + R_{LOAD}} \cdot \left(C_{OUT_INT} + C_{OUT_EXT}\right)}$$

Compensation Mid-Band Gain:

$$G_{MB} = 20 \log \frac{R_3}{R_1}$$
 [1]

Compensation Zero:

$$F_{Z1} = \frac{1}{2\pi \cdot R_2 \cdot C_1}$$
 [2]

Compensation Pole:

$$F_{P2} = \frac{1}{2\pi \cdot \frac{R_3 \cdot C_1 \cdot C_2}{C_1 + C_2}}$$

and for $F_{P2} >> F_{Z1} (C_1 + C_2 \approx C_1)$:

$$F_{P2} \approx \frac{1}{2\pi \cdot R_3 \cdot C_2}$$
 [3]



8.2.4 Midband Gain Design (R1,R3):

With reference to Figure 27: curve ABC is the:

- minimum output voltage in the application
- maximum input voltage expected in the application
- maximum load

PRM® open loop response, and is where the maximum crossover frequency occurs. In order for the maximum crossover frequency to occur at the design choice F_{CMAX} , the compensation gain must be equal and opposite of the powertrain gain at this frequency. For stability purposes, the compensation should be in the Mid-band (J-K) at the crossover. Using Equation [1], the mid-band gain can be selected appropriately.

8.2.5 Compensation Zero Design (C1):

With reference to Figure 27: curve EFG is the:

- maximum output voltage in the application
- minimum input voltage expected in the application
- minimum load in the application

PRM open loop response, and is where the minimum crossover frequency F_{CMIN} occurs. Based on stability criteria, the compensation must be in the mid-band at the minimum crossover frequency, therefore F_{CMIN} will occur where EFG is equal and opposite of G_{MB} . C1 can be selected using Equation [2] so that F_{Z1} occurs prior to F_{CMIN} .

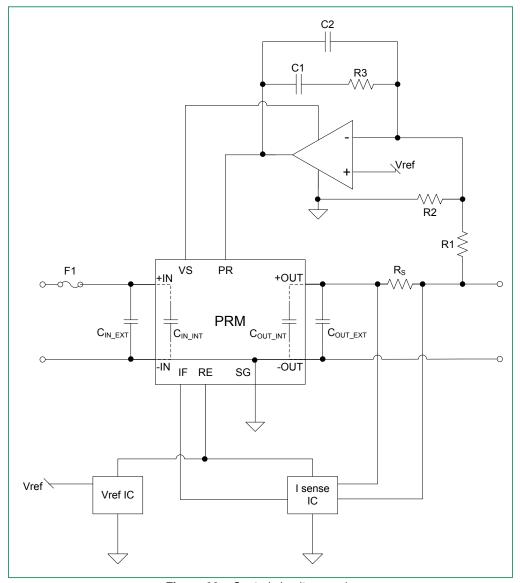


Figure 26 - Control circuit example

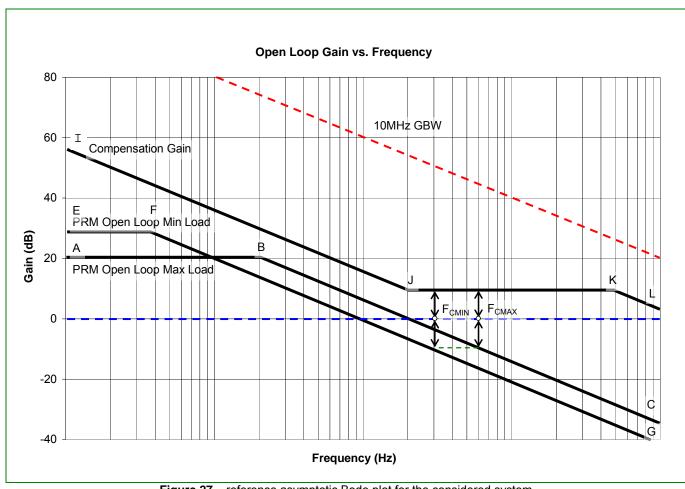


Figure 27 – reference asymptotic Bode plot for the considered system

8.2.6 High Frequency Pole Design (C2):

Using Equation [3], C2 should be selected so that F_{P2} is at least one decade above F_{CMAX} and prior to the gain bandwidth product of the operational amplifier (10MHz for this example). For applications with a higher desired crossover frequency the use of a high gain bandwidth product amplifier may be necessary to ensure that the real pole can be set at least one decade above the maximum crossover frequency.

8.2.7 Verifying Stability:

The preferred method for verifying stability is to use a network analyzer, measuring the closed loop response across various lines and load conditions.

In the absence of a network analyzer, a load step transient response can be used in order to estimate stability.

Figure 28 illustrates an example of a load step response. Equation [4] can be used to predict the phase margin

based on the ratio of the "kick" to "droop" (as defined in Fig. 28).

1 ig. 20<u>).</u>

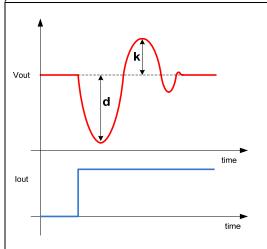


Figure 28 – load step response example and "droop" vs. "kick" definition

$$\Phi_{m} \approx 100 \sqrt{\frac{\left(\ln\frac{k}{d}\right)^{2}}{\left(\ln\frac{k}{d}\right)^{2} + \pi^{2}}}$$
 [4]

8.3 Burst Mode Operation:

At light loads, the PRM[®] will operate in a burst mode due to minimum timing constraints. An example burst operation waveform is illustrated in Figure 29.

For very light loads, and also for higher input voltages, the minimum time power switching cycle from the powertrain will exceed the power required by the load. In this case the external error amplifier will periodically drive PR below the switching threshold in order to maintain regulation. Switching will cease momentarily until the error amplifier once again drives PR voltage above the threshold.

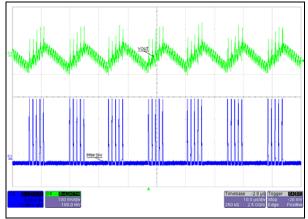


Figure 29 - light load burst mode of operation

Note that during the bursts of switching, the powertrain frequency is constant, but the number of pulses as well as the time between bursts is variable. The variability depends on many factors including input voltage, output voltages, load impedance, and external error amplifier output impedance.

In burst mode, the gain of the PR input to the plant which is modeled in the previous sections is time varying. Therefore the small signal analysis can not be directly applied to burst mode operation.

8.4 Input and Output filter design

Figures 14 and 15 provide the total input and output charge per cycle, as well as switching frequency, of the PRM at full load under various input and output voltages conditions.

Figure 20 provides the effective internal capacitance of the module. A conservative estimate of input and output peakpeak voltage ripple at nominal line and trim is provided by equation [5]:

$$\Delta V = \frac{Q_{TOT} - \frac{I_{FL} \cdot 0.4}{f_{SW}}}{C_{INT} + C_{EXT}}$$
 [5]

 Q_{TOT} is the total input (Fig. 15) or output (Fig. 14) charge per switching cycle at full load, while C_{INT} is the module internal effective capacitance at the considered voltage (Fig. 20) and C_{EXT} is the external effective capacitance at the considered voltage.

8.5 Input filter stability

The PRM can provide very high dynamic transients. It is therefore very important to verify that the voltage supply source as well as the interconnecting line are stable and do not oscillate. For this purpose, the converter dynamic input impedance magnitude $\left|r_{EQ_IN}\right|$ is provided in Figures 22, 23, 24. It is recommended to provide adequate design margin with respect to the stability conditions illustrated in 10.5.1 and 10.5.2.

8.5.1 Inductive source and local, external input decoupling capacitance with negligible ESR (i.e.: ceramic type)

The voltage source impedance can be modeled as a series $R_{\text{line}}L_{\text{line}}$ circuit. The high performance ceramic decoupling capacitors will not significantly damp the network because of their low ESR; therefore in order to guarantee stability the following conditions must be verified:

$$R_{line} > \frac{L_{line}}{\left(C_{IN_INT} + C_{IN_EXT}\right) \cdot \left|r_{EQ_IN}\right|} \quad [6]$$

$$R_{line} \ll \left| r_{EO-IN} \right| \tag{7}$$

It is critical that the line source impedance be at least an octave lower than the converter's dynamic input resistance, [7]. However, R_{line} cannot be made arbitrarily low otherwise equation [6] is violated and the system will show instability, due to under-damped RLC input network.



8.5.2 Inductive source and local, external input decoupling capacitance with significant $R_{\text{CIN_EXT}}$ ESR (i.e.: electrolytic type)

In order to simplify the analysis in this case, the voltage source impedance can be modeled as a simple inductor $L_{\text{line}}.$ Notice that, the high performance ceramic capacitors $C_{\text{IN_INT}}$ within the PRM should be included in the external electrolytic capacitance value for this purpose. The stability criteria will be

$$\left| r_{EQ_IN} \right| > R_{C_{IN}} \tag{8}$$

$$\frac{L_{line}}{C_{IN_EXT} \cdot R_{C_{IN_EXT}}} < \left| r_{EQ_IN} \right|$$
 [9]

Equation [9] shows that if the aggregate ESR is too small – for example by using very high quality input capacitors (C_{IN_EXT}) – the system will be under-damped and may even become destabilized. Again, an octave of design margin in satisfying [8] should be considered the minimum.

8.6 Arrays

Up to ten PRMs of the same type may be placed in parallel to expand the power capacity of the system. The following high-level guidelines must be followed in order for the resultant system to start up and operate properly, and to avoid overstress or exceeding any absolute maximum ratings.

- IN pins of all PRMs must be connected together. Both inductance and resistance from the common power source to each PRM should be minimized, and matched.
- Input voltage to all PRMs must be the same. Independent fuses for each PRM are recommended.
- > PC pins must be connected together for synchronization and proper fault response.
- Reference supply to the control loop voltage reference and current sense circuitry must be enabled when all modules' RE pins have reached their operational voltage levels.
- There must be one single external voltage control loop. The control loop must drive each PR pin relative to each module's SG pin, and the local PR voltage must be the same across all modules.
- Each PRM must have its own local current shunt and current sense circuitry to drive its IF pin.
- The number of PRMs required to achieve a given array capacity must consider all sources of mismatch to avoid overstress of any PRM in the

- array. Imbalances in sharing are not only due to current sharing accuracy specifications, but also temperature differences among PRMs, Vin variations, and error terms in the buffering of the error amplifier output to the PR pins.
- Control loop compensation procedures above will hold for an array, in general, although many parameters must be scaled against the number of PRMs in the system.

Please contact Vicor Applications for assistance.

8.7 Input Fuse Recommendations

A fuse should be incorporated at the input to each PRM, in series with the +IN pin. A 10 A or smaller input fuse (Littelfuse® NANO^{2®} 451/453 Series, or equivalent) is required to safety agency conditions of acceptability. Always ascertain and observe the safety, regulatory, or other agency specifications that apply to your specific application.

8.8 Layout considerations

Application Note AN:005 details board layout using V•I Chip components. Additional consideration must be given to the external control circuit components.

The current sense shunt signal voltage is highly sensitive to noise. As such, current sensing circuitry should be located close to the shunt to minimize the length of the sense signals. A Kelvined connection at the shunt is recommended for best results.

The control signal from a remote voltage sense circuit to the PRM should be shielded. Avoid routing this, or other control signals directly underneath the PRM, if possible. Components that tie directly to the PRM should be located close to their respective pins. It is also critical that all control components be referenced to SG, and that SG not be tied to any other ground in the system, including –IN or –OUT of the PRM.



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